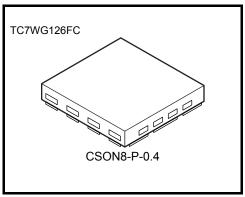
TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7WG126FC

Dual Bus Buffer with 3-STATE Output

Features

- High-level output current: $I_{OH}/I_{OL} = \pm 8 \text{ mA (min)}$
 - at $V_{CC} = 3 V$
- High-speed operation: t_{pd} = 2.5 ns (typ.)
 - at $V_{CC} = 3.3 \text{ V}, 15 \text{pF}$
- Operating voltage range: V_{CC} = 0.9~3.6 V
- 5.5-V tolerant inputs
- 3.6-V power down protection outputs



Weight: 0.002 g (typ.)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Value	Unit
Power supply voltage	V _{CC}	-0.5~4.6	V
DC input voltage	V _{IN}	-0.5~7.0	V
DC output voltage	V	-0.5~4.6 (Note 1)	٧
DC output voltage	Vout	-0.5~V _{CC} + 0.5 (Note 2)	V
Input diode current	I _{IK}	-20	mA
Output diode current	lok	-20 (Note 3)	mA
DC output current	lout	±25	mA
DC V _{CC} /GND current	Icc	±100	mA
Power dissipation	PD	150 (Note 4)	mW
Storage temperature	T _{stg}	-65~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: V_{CC} = 0 V

Note 2: High or Low State.

IOUT absolute maximum rating must be observed.

Note 3: V_{OUT} < GND

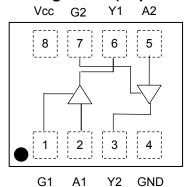
Note 4: Mounted on an FR4 board.

 $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 1.6 \text{ t}, \text{ Cu Pad: } 11.56 \text{ mm}^2)$

Marking

Product name

Pin Assignment (top view)

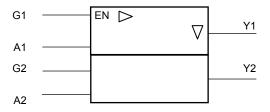


Truth Table

Inp	Outputs	
G	А	Y
L	Χ	Z
Н	L	L
Н	Н	Н

X: Don't Care Z: High impedance

IEC Logic Symbol



Operating Ranges

Characteristics	Symbol	Value	Unit	
Power supply voltage	V _{CC}	0.9~3.6	V	
Input voltage	V _{IN}	0~5.5	V	
Output valtage	\/a	0~3.6 (Note 5)	٧	
Output voltage	V _{OUT}	0~V _{CC} (Note 6)	\ \ \	
		±8.0 (Note 7)		
		±4.0 (Note 8)	mA	
Output Current		±3.0 (Note 9)		
Output Current	I _{OH} /I _{OL}	±1.7 (Note 10)		
		±0.3 (Note 11)		
		±0.02 (Note 12)		
Operating temperature	T _{opr}	-40~85	°C	
Input rise and fall time	dt/dV	0~10 (Note 13)	ns/V	

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Note 5: $V_{CC} = 0 V$

Note 6: High or Low state.

Note 7: $V_{CC} = 3.0 \sim 3.6 \text{ V}$

Note 8: $V_{CC} = 2.3 \sim 2.7 \text{ V}$

Note 9: $V_{CC} = 1.65 \sim 1.95 \text{ V}$

Note 10: $V_{CC} = 1.4 \sim 1.6 \text{ V}$

Note 11: $V_{CC} = 1.1 \sim 1.3 \text{ V}$

Note 12: $V_{CC} = 0.9 \text{ V}$

Note 13: $V_{IN} = 0.8 \sim 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$

Electrical Characteristics

DC Characteristics

Characteristics		Symbol	Toot	Condition		-	Га = 25°C)	Ta = -4	0~85°C	Unit		
Ondiacionatios Syl		Syllibol	ol Test Condition		V _{CC} (V)	Min	Тур.	Max	Min	Max	Onit		
					0.9	V _C C	_	_	V _C C	_			
					1.1~1.3	V _{CC} × 0.7	_	_	V _{CC} × 0.7	_			
	High level	V _{IH}		_		V _{CC} × 0.65	_	_	V _{CC} × 0.65	_			
					1.65~ 1.95	V _{CC} × 0.65	_	_	V _{CC} × 0.65	_			
					2.3~2.7	1.7			1.7	_			
Input voltage					3.0~3.6	2.0			2.0	_	V		
input voltage					0.9	_		GND	_	GND	V		
					1.1~1.3	_	_	V _{CC} × 0.3	_	V _{CC} × 0.3			
	Low level	V _{IL}		_	1.4~1.6	_	_	V _{CC} × 0.35	_	V _{CC} × 0.35			
					1.65~ 1.95	_		V _{CC} × 0.35	_	V _{CC} × 0.35			
					2.3~2.7	_		0.7	_	0.7			
							3.0~3.6	_	_	0.8	_	0.8	
				I _{OH} =-0.02 mA	0.9	0.75	_	_	0.75	_			
	High level V _{OH}			$I_{OH} = -0.3 \text{ mA}$	1.1~1.3	V _{CC} × 0.75		_	V _{CC} × 0.75	_			
		Vон	V _{IN} =V _{IH}	$I_{OH} = -1.7 \text{ mA}$	1.4~1.6	V _{CC} × 0.75			V _{CC} × 0.75				
				$I_{OH} = -3.0 \text{ mA}$	1.65~ 1.95	V _{CC} -0.45			V _{CC} -0.45		. v		
				$I_{OH} = -4.0 \text{ mA}$	2.3~2.7	2.0	_	_	2.0	_			
Output voltage				$I_{OH} = -8.0 \text{ mA}$	3.0~3.6	2.48	_	_	2.48	_			
Output Voltage				$I_{OL} = 0.02 \text{ mA}$	0.9	_	_	0.1	_	0.1			
				$I_{OL} = 0.3 \text{ mA}$	1.1~1.3	_		V _{CC} × 0.25	_	V _{CC} × 0.25			
	Low level	V _{OL}	V _{IN} = V _{IL}	I _{OL} = 1.7 mA	1.4~1.6	_		V _{CC} × 0.25	_	V _{CC} × 0.25			
			or viH	I _{OL} = 3.0 mA	1.65~ 1.95	_		0.45	_	0.45			
				I _{OL} = 4.0 mA	2.3~2.7	_	_	0.4	_	0.4			
				$I_{OL} = 8.0 \text{ mA}$	3.0~3.6	_	_	0.4	_	0.4			
Input leakage current I _{II}		I _{IN}	V _{IN} = 0~5.5V		0~3.6		_	±0.1		±1.0	μА		
3-state output off-s	state current	I _{OZ}	V _{IN} = V _{IH} V _{OUT} = 0	or V _{IL} ~3.6V	0.9~3.6	_	_	1.0	_	10.0	μА		
Power off leakage	current	l _{OFF}	V _{IN} = 5.5\ or V _{OUT} =	= 3.6V	0.0	_		1.0	_	10.0	μА		
Quiescent supply of	current	Icc	$V_{IN} = V_{CO}$	or GND	3.6	_	_	1.0	_	10.0	μА		

AC Characteristics (Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition			Га = 25°(Ta = -40~85°C		Unit
Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Тур.	Max	Min	Max	Oill
			0.9	_	18.3	_	_	_	
			1.1~1.3	_	9.4	18.4	1.0	34.9	
		C _L = 10 pF,	1.4~1.6	_	5.5	8.5	1.0	10.7	
		$R_L = 1 M\Omega$	1.65~ 1.95	_	4.2	6.2	1.0	6.7	
			2.3~2.7	_	2.8	3.9	1.0	4.4	
			3.0~3.6	_	2.3	3.1	1.0	3.7	
			0.9		21.2	_	_	_	
			1.1~1.3	_	10.7	21.5	1.0	38.0	
Propagation delay time	t _{pLH}	C _L = 15 pF,	1.4~1.6	_	6.1	9.3	1.0	11.9	ns
Fropagation delay time	t_{pHL}	$R_L = 1 M\Omega$	1.65~ 1.95	_	4.7	6.9	1.0	7.1	115
			2.3~2.7		3.1	4.4	1.0	5.0	
			3.0~3.6	_	2.5	3.4	1.0	3.9	
		$C_L = 30 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9	_	30.5	_	_	_	
			1.1~1.3		14.9	30.0	1.0	58.1	
			1.4~1.6		8.2	13.2	1.0	16.6	
			1.65~ 1.95		6.1	9.2	1.0	9.9	
			2.3~2.7		4.1	5.7	1.0	6.1	
			3.0~3.6		3.4	4.4	1.0	4.8	
		$C_L = 10 \text{ pF},$ $R_L = 100 \text{ k}\Omega$ $C_L = 10 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	0.9		24.0	_	_	_	
			1.1~1.3	_	11.8	22.5	1.0	35.8	
			1.4~1.6		6.8	10.4	1.0	12.0	
			1.65~ 1.95		5.1	7.3	1.0	8.1	
			2.3~2.7	1	3.4	4.6	1.0	5.3	
			3.0~3.6		2.5	3.4	1.0	3.9	
		$\begin{aligned} C_L &= 15 \text{ pF}, \\ R_L &= 100 \text{ k}\Omega \end{aligned}$	0.9	_	26.6	_	_	_	
			1.1~1.3	_	13.0	25.0	1.0	41.9	
Output enable time	t _{pZL}		1.4~1.6	_	7.4	11.4	1.0	13.4	ns
	t _{pZH}	$C_L = 15 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65~ 1.95		5.5	7.9	1.0	8.5	
		_	2.3~2.7		3.7	4.9	1.0	5.5	
			3.0~3.6	_	3.0	4.1	1.0	4.6	
		$\begin{array}{c} C_L = 30 \text{ pF}, \\ R_L = 100 \text{ k}\Omega \end{array}$	0.9	_	36.4	_	_	_	
			1.1~1.3	_	17.9	35.8	1.0	59.1	
			1.4~1.6	_	9.8	15.3	1.0	17.8	
		$C_L = 30 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65~ 1.95	_	7.2	10.5	1.0	11.2	
			2.3~2.7	_	4.5	5.9	1.0	6.6	
	<u> </u>		3.0~3.6		3.6	4.6	1.0	5.3	

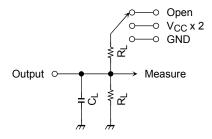
Characteristics	Symbol Test Condition			Га = 25°C)	Ta = -4	0~85°C	Unit					
Characteristics	Syllibol	rest Condition	V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic				
		$C_L = 10 \text{ pF},$ $R_L = 100 \text{ k}\Omega$	0.9	_	168.6	_	_	_					
			1.1~1.3	_	9.5	18.4	1.0	25.2					
			1.4~1.6	_	7.5	9.5	1.0	10.6					
		$C_L = 10 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65~ 1.95	_	7.1	8.7	1.0	9.6					
			2.3~2.7	_	6.8	7.9	1.0	8.8					
			3.0~3.6	_	6.5	7.5	1.0	8.4					
	t _{pLZ} t _{pHZ}	$C_L = 15 \text{ pF},$ $R_L = 100 \text{ k}\Omega$	0.9	_	201.8	_	_						
		$C_L = 15 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.1~1.3	_	10.5	19.8	1.0	27.6	ns				
Output disable time			1.4~1.6		9.0	10.4	1.0	12.3					
							1.65~ 1.95	_	8.5	9.7	1.0	10.6	
					2.3~2.7	_	7.9	8.8	1.0	10.3			
						3.0~3.6	_	7.6	8.3	1.0	9.5		
		$\begin{array}{c} C_L = 30 \text{ pF}, \\ R_L = 100 \text{ k}\Omega \end{array}$	0.9	_	251.5	_	_						
			1.1~1.3		14.1	23.8	1.0	31.9					
			1.4~1.6		13.5	14.5	1.0	16.0					
		$C_L = 30 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65~ 1.95		12.7	14.3	1.0	15.0					
		_	2.3~2.7		12.2	14.1	1.0	14.7					
			3.0~3.6	_	11.9	13.8	1.0	14.4					
Input capacitance	C _{IN}	_	3.6		3		_	_	pF				
Power dissipation capacitance	C _{PD}	(Note 14)	0.9 ~ 3.6	_	10	_	_	_	pF				

Note 14:C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$

AC Characteristics Measurement Circuit



Characteristics	Switch
t _{pLH} , t _{pHL}	Open
t _{pLZ} , t _{pZL}	V _{CC} x 2
t _{pHZ} , t _{pZH}	GND

Figure1 t_{pLH}, t_{pHL}

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AC Waveforms

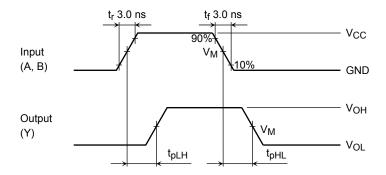


Figure 2 tpLH, tpHL

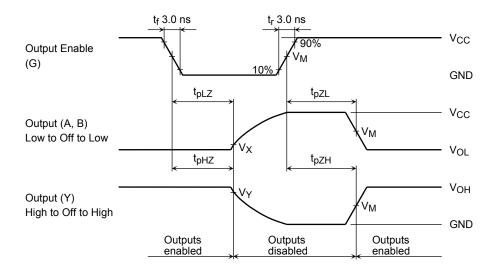


Figure 3 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

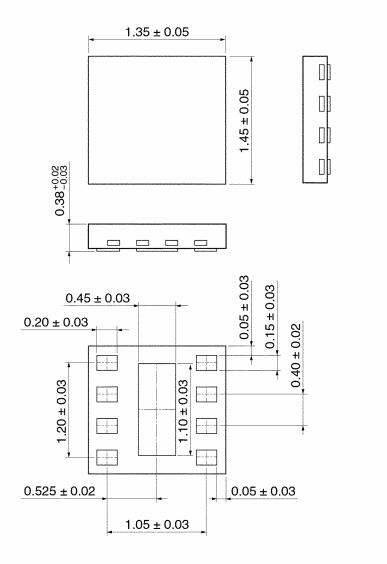
unit			V ₍	CC		
dilit	3.3±0.3 V	2.5±0.2 V	1.8±0.15 V	1.5±0.1 V	1.2±0.1 V	0.9 V
V_{M}	V _{CC} / 2	V _{CC} / 2	V _{CC} / 2	V _{CC} / 2	V _{CC} / 2	V _{CC} / 2
VX	V _{OL} + 0.3 V	V _{OL} + 0.15 V	V _{OL} + 0.15 V	V _{OL} + 0.1 V	V _{OL} + 0.1 V	V _{OL} + 0.1 V
VY	V _{OH} - 0.3 V	V _{OH} - 0.15 V	V _{OH} - 0.15 V	V _{OH} - 0.1 V	V _{OH} - 0.1 V	V _{OH} - 0.1 V

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Package Dimensions

CSON8-P-0.4 Unit: mm



Weight: 0.002 g (Typ.)

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20070701-EN GENERAL

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